

# **Excellent Integrated System Limited**

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<u>Vishay Semiconductor/Diodes Division</u> <u>VF20120SG-M3/4W</u>

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### Distributor of Vishay Semiconductor/Diodes Division: Excellent Integrated System Limite Datasheet of VF20120SG-M3/4W - DIODE SCHOTTKY 20A 120V ITO220AB

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### VF20120SG

COMPLIANT

**FREE** 

Vishay General Semiconductor

## **High-Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.54 \text{ V}$  at  $I_F = 5 \text{ A}$ 





PRIMARY CHARACTERISTICS			
I <sub>F(AV)</sub>	20 A		
$V_{RRM}$	120 V		
I <sub>FSM</sub>	150 A		
$V_F$ at $I_F = 20 A$	0.78 V		
T <sub>J</sub> max.	150 °C		
Package	ITO-220AB		

Single die

Diode variation

#### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder bath temperature 275 °C max. 10 s, per JESD 22-B106
- · Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

#### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

#### **MECHANICAL DATA**

Case: ITO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL	VF20120SG	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	120	V	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	20	А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150	А	
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000	V/µs	
Isolation voltage from termal to heatsink t = 1 min	V <sub>AC</sub>	1500	V	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-40 to +150	°C	







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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNIT	
Instantaneous forward voltage	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.62	-	V	
	I <sub>F</sub> = 10 A			0.81	-		
	I <sub>F</sub> = 20 A			1.20	1.33		
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.54	-		
	I <sub>F</sub> = 10 A			0.65	-		
	I <sub>F</sub> = 20 A			0.78	0.88		
Reverse current	V <sub>B</sub> = 90 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	10	-	μΑ	
	V <sub>R</sub> = 90 V	T <sub>A</sub> = 125 °C		7	ı	mA	
	V <sub>B</sub> = 120 V	T <sub>A</sub> = 25 °C		-	250	μA	
	v <sub>R</sub> = 120 v	T <sub>A</sub> = 125 °C		12	25	mA	

#### Notes

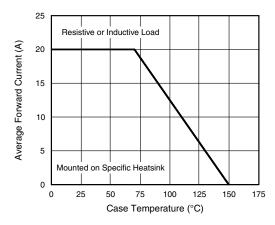
(1) Pulse test: 300 µs pulse width, 1 % duty cycle

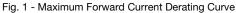
(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)				
PARAMETER	SYMBOL VF20120SG U			
Typical thermal resistance	$R_{\theta JC}$	4.2	°C/W	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VF20120SG-M3/4W	1.75	4W	50/tube	Tube

## RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)





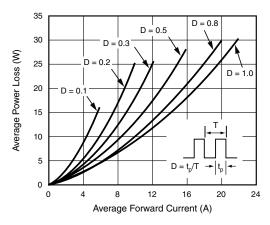


Fig. 2 - Forward Power Dissipation Characteristics



## VF20120SG

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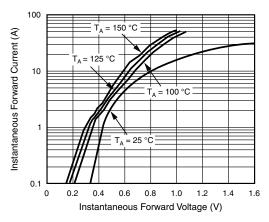


Fig. 3 - Typical Instantaneous Forward Characteristics

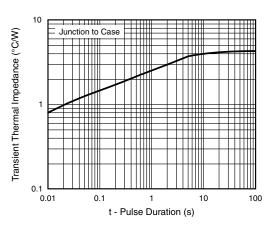


Fig. 5 - Typical Transient Thermal Impedance

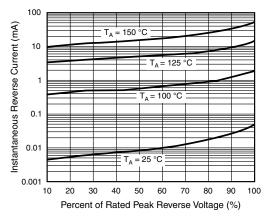


Fig. 4 - Typical Reverse Characteristics

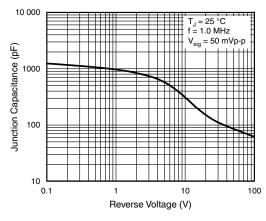
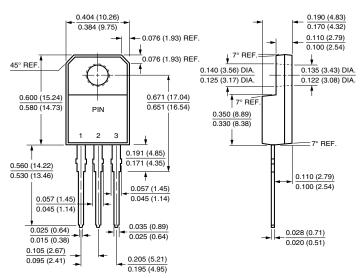


Fig. 6 - Typical Junction Capacitance

#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

#### ITO-220AB



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